

Standard Recovery Diodes (Hockey PUK Version), 1600 A



DO-200AB (B-PUK)

FEATURES

- Wide current range
- High voltage ratings up to 3000 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style DO-200AB (B-PUK)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

PRODUCT SUMMARY

$I_{T(AV)}$	1600 A
Package	DO-200AB (B-PUK)
Circuit configuration	Single diode

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		1600	A
	T_{hs}	55	°C
$I_{F(RMS)}$		3010	A
	T_{hs}	25	°C
I_{FSM}	50 Hz	16 600	A
	60 Hz	17 400	
I^2t	50 Hz	1386	kA ² s
	60 Hz	1265	
V_{RRM}	Range	400 to 3000	V
T_J		-40 to 180	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-SD1500C..L	04	400	500	50
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	25	2500	2600	
	30	3000	3100	



FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average forward current at heatsink temperature	I _{F(AV)}	180° conduction, half sine wave Double side (single side) cooled			1600 (820)	A	
					55 (85)	°C	
Maximum RMS forward current	I _{F(RMS)}	25 °C heatsink temperature double side cooled			3010	A	
Maximum peak, one cycle, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reappplied	Sinusoidal half wave, initial T _J = T _J maximum	16 600		
		t = 8.3 ms			17 400		
		t = 10 ms	100 % V _{RRM} reappplied		14 000		
		t = 8.3 ms			14 700		
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reappplied		1386		kA ² s
		t = 8.3 ms			1265		
		t = 10 ms	100 % V _{RRM} reappplied		980		
		t = 8.3 ms			895		
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reappplied			13 860	kA ² √s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J maximum			0.83	V	
High level value of threshold voltage	V _{F(TO)2}	(I > π × I _{F(AV)}), T _J = T _J maximum			0.95		
Low level value of forward slope resistance	r _{f1}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J maximum			0.27	mΩ	
High level value of forward slope resistance	r _{f2}	(I > π × I _{F(AV)}), T _J = T _J maximum			0.25		
Maximum forward voltage drop	V _{FM}	I _{pk} = 3000 A T _J = T _J maximum, t _o = 10 ms sinusoidal wave			1.64	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES UNITS
Maximum junction operating temperature range	T_J				-40 to 180 °C
Maximum storage temperature range	T_{Stg}				-55 to 200
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation single side cooled			0.073
		DC operation double side cooled			0.031
Mounting force, ± 10 %					14 700 (1500) N (kg)
Approximate weight					255 g
Case style		See dimensions - link at the end of datasheet			DO-200AB (B-PUK)

ΔR_{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	Single Side	Double Side	Single Side	Double Side		
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum	K/W
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.035	0.035	0.036	0.036		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

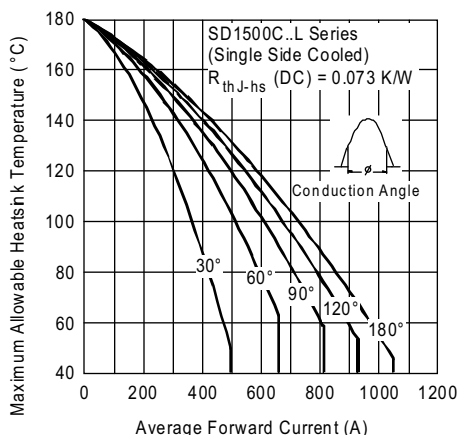


Fig. 1 - Current Ratings Characteristics

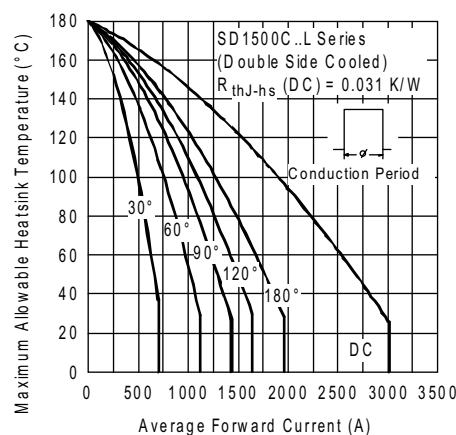


Fig. 4 - Current Ratings Characteristics

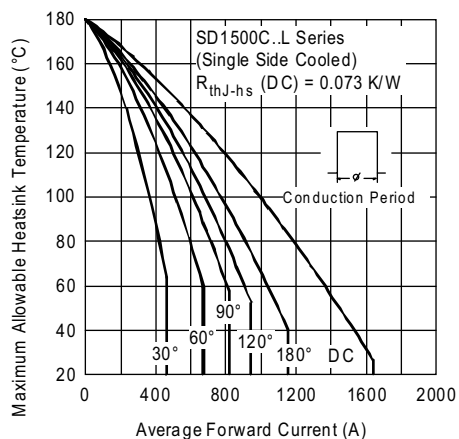


Fig. 2 - Current Ratings Characteristics

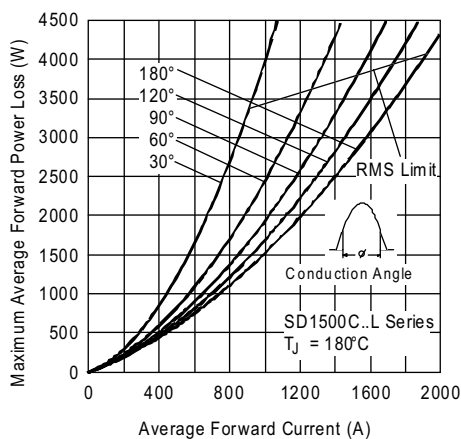


Fig. 5 - Forward Power Loss Characteristics

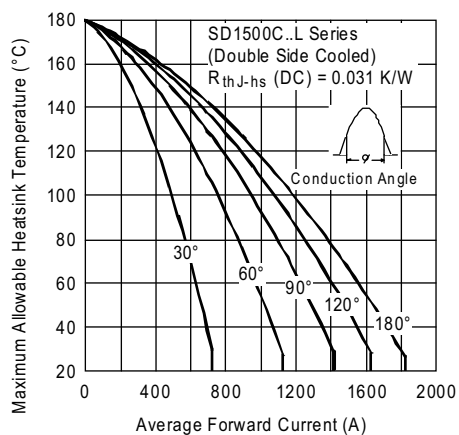


Fig. 3 - Current Ratings Characteristics

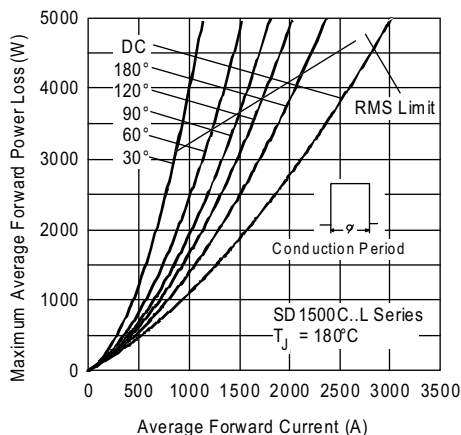


Fig. 6 - Forward Power Loss Characteristics

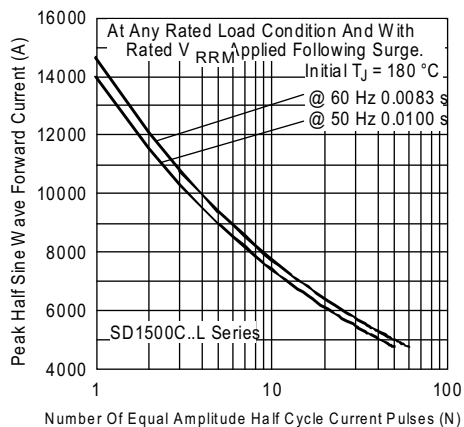


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

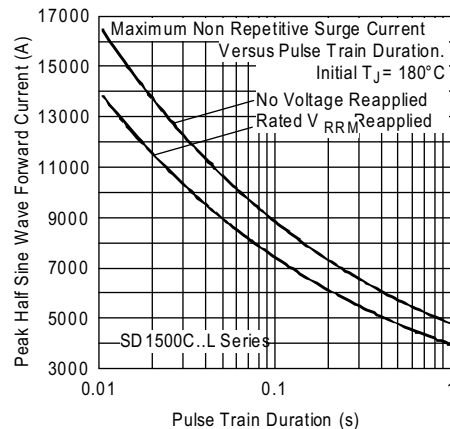


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

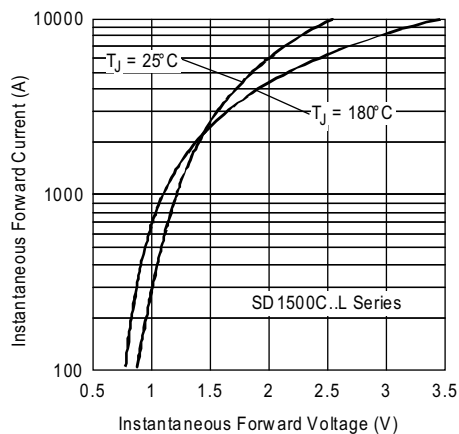


Fig. 9 - Forward Voltage Drop Characteristics

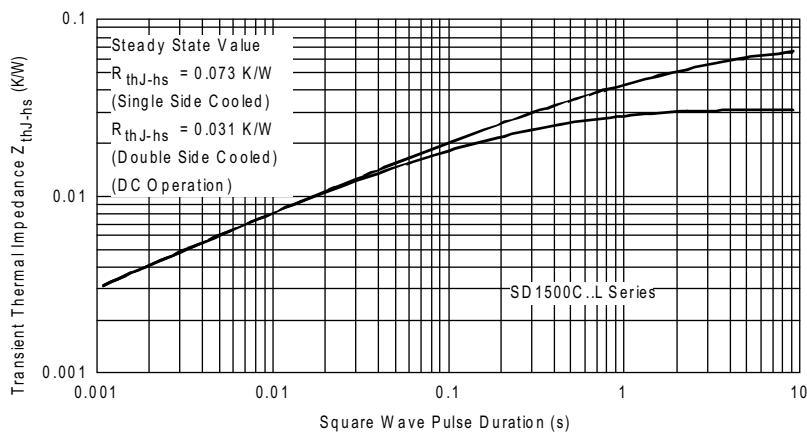


Fig. 10 - Thermal Impedance Z_{thJC} Characteristics



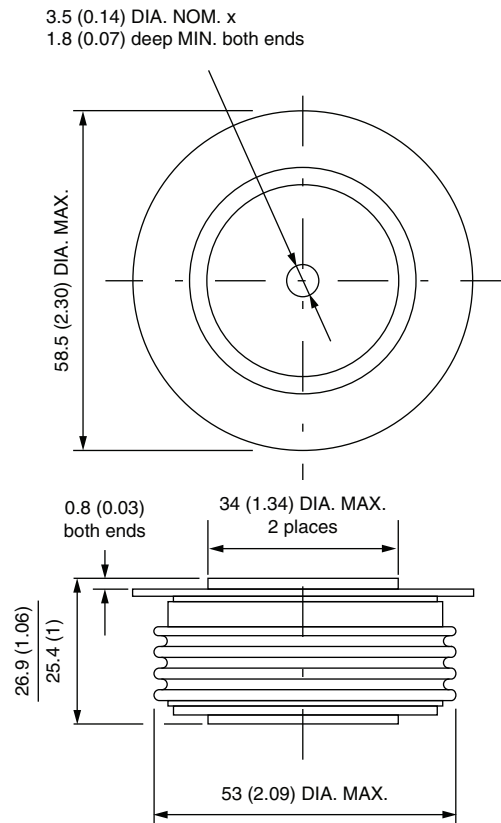
ORDERING INFORMATION TABLE

Device code	VS-	SD	150	0	C	30	L
	①	②	③	④	⑤	⑥	⑦
①	- Vishay Semiconductors product						
②	- Diode						
③	- Essential part number						
④	- 0 = Standard recovery						
⑤	- C = Ceramic PUK						
⑥	- Voltage code x 100 = V_{RRM} (see Voltage Ratings table)						
⑦	- L = PUK case DO-200AB (B-PUK)						

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95246

DO-200AB (B-PUK)

DIMENSIONS in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)



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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9